



Contribution ID: 59

Type: Oral

Giant dielectric properties with excellent temperature stability of $(\text{Ga}_{0.5}\text{Nb}_{0.5})\text{xTi}_{1-\text{x}}\text{O}_2$ ceramics

Thursday, 25 May 2017 13:45 (15 minutes)

In this work, we investigate the giant dielectric properties of $(\text{Ga}_{0.5}\text{Nb}_{0.5})\text{xTi}_{1-\text{x}}\text{O}_2$ (where $x=0.01, 0.025, 0.05$ and 0.1) prepared by a solid state reaction method. The phase composition, microstructure, and oxidation state are characterized by X-ray diffraction, field-emission scanning electron microscopy and X-ray photoelectron spectroscopy, respectively. The single phase of rutile- TiO_2 with dense microstructure are obtained in all sintered $(\text{Ga}_{0.5}\text{Nb}_{0.5})\text{xTi}_{1-\text{x}}\text{O}_2$ ceramics. The existence of Ti^{3+} and oxygen vacancies are confirmed. The dielectric constant increased with increasing co-doping $(\text{Ga}+\text{Nb})$ concentration. Excellent dielectric properties are obtained in the $(\text{Ga}_{0.5}\text{Nb}_{0.5})\text{xTi}_{1-\text{x}}\text{O}_2$ ceramic with $x=0.1$ sintered at 1550°C for 1h. Low dielectric loss tangent (< 0.05) and very large dielectric constant ($\epsilon = 41267$) with excellent temperature coefficient ($< \pm 15\%$) in the range of -70 to 170°C are achieved. The giant dielectric response over a broad temperature range of the $(\text{Ga}_{0.5}\text{Nb}_{0.5})\text{xTi}_{1-\text{x}}\text{O}_2$ ceramics is primarily attributed to the interfacial polarization at internal insulating interfaces.

Keyword: TiO_2 , Giant dielectric permittivity, Temperature coefficient, Electron-pinned defect-dipole.

Primary authors: Mr TUICHAI, Wattana (KhonKaen University); Dr THONGBAI, Prasit (Integrated Nanotechnology Research Center (INRC), Department of Physics, Faculty of Science, KhonKaen University, KhonKaen 40002, Thailand)

Co-authors: Dr DANWITTAYAKUL, Supamas (National Metal and Materials Technology Center, National Science and Technology Development Agency, 114 Thailand Science Park, Paholyothin Rd, Klong 1, Klong Luang, Pathumthani 12120, Thailand); Dr CHANLEK, Narong (Synchrotron Light Research Institute (Public Organization), 111 University Avenue, Muang District, NakhonRatchasima 30000, Thailand); Prof. MAENSIRI, Santi (School of Physics, Institute of Science, Suranaree University of Technology, Nakhon Ratchasima 30000, Thailand)

Presenter: Mr TUICHAI, Wattana (KhonKaen University)

Session Classification: A13: Material Physics

Track Classification: Material Physics and Functional Materials